CMOS Digital Integrated Circuits Silicon Monolithic

74VHC595FT

1. Functional Description

• 8-Bit Shift Register/Latch (3-state)

2. General

The 74VHC595FT is an advanced high speed 8-BIT SHIFT REGISTER/LATCH fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHC595FT contains an 8-bit static shift register which feeds an 8-bit storage register.

Shift operation is accomplished on the positive going transition of the SCK input. The output register is loaded with the contents of the shift register on the positive going transition of the RCK input.

Since RCK and SCK signal are independent, parallel outputs can be held stable during the shift operation. And, since the parallel outputs are 3-state, it can be directly connected to 8-bit bus. This register can be used in serial-to-parallel conversion, data receivers, etc.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems

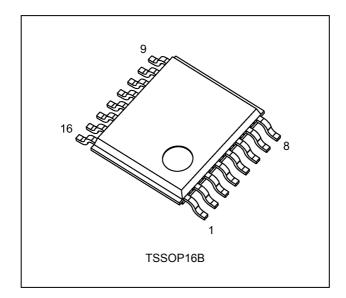
such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

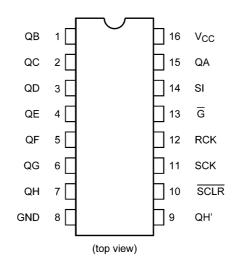
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $f_{MAX} = 185$ MHz (typ.) at $V_{CC} = 5.0$ V
- (4) Low power dissipation: $I_{CC} = 4.0 \ \mu A \ (max)$ at $T_a = 25^{\circ}C$
- (5) High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$ (min)
- (6) Power-down protection is provided on all inputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V to } 5.5 \text{ V}$
- (9) Low noise: $V_{OLP} = 1.0 V (max)$
- (10) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 595 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.



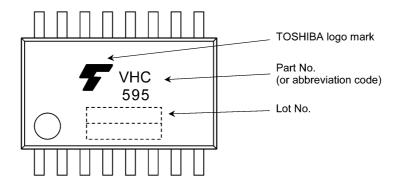
4. Packaging



5. Pin Assignment

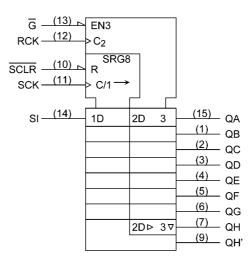


6. Marking



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7. IEC Logic Symbol



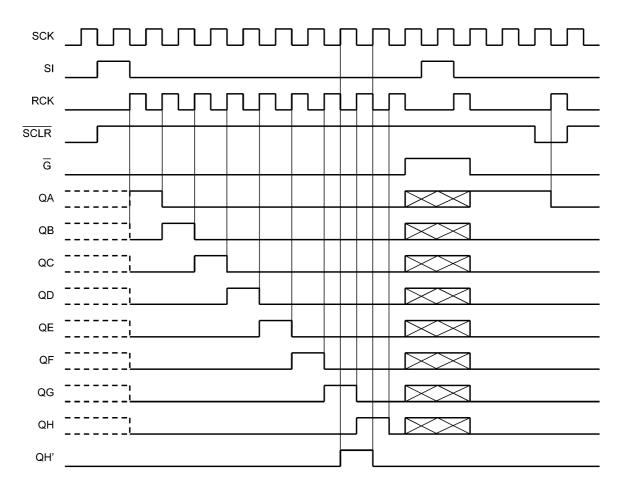
8. Truth Table

		Inputs			Function
SI	SCK	SCLR	RCK	G	Fulction
х	X	Х	х	н	QA thru QH outputs disable
Х	X	Х	Х	L	QA thru QH outputs enable
х	X X L X X			Х	Shift register is cleared.
L		н	х	х	First stage of S.R. becomes "L". Other stages store the data of previous stage, respectively.
н		Н	х	х	First stage of S.R. becomes "H". Other stages store the data of previous stage, respectively.
Х		н	х	Х	State of S.R. is not changed.
х	Х	х		х	S.R. data is stored into storage register.
х	Х	Х		х	Storage register stage is not changed.

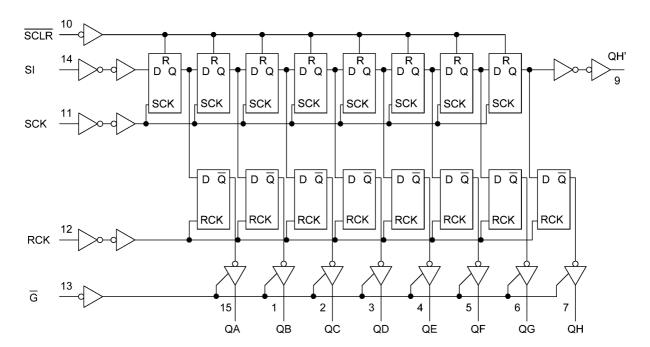
X: Don't care

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9. Timing Chart



10. System Diagram



11. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		-20	mA
Output diode current	I _{ОК}		±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	PD	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

12. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V_{CC} = 5.0 \pm 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

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13. Electrical Characteristics

13.1. DC Characteristics (Unless otherwise specified, $T_a = 25 \text{ °C}$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	_	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	—	
Low-level input voltage	VIL	—		2.0	—	_	0.50	V
				3.0 to 5.5	—	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	2.0	—	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			I _{OH} = -4 mA	3.0	2.58	_	—	
			I _{OH} = -8 mA	4.5	3.94	_	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	2.0	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			I _{OL} = 4 mA	3.0	—	_	0.36	
			I _{OL} = 8 mA	4.5	—	_	0.36	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	_	±0.25	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	_	±0.1	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μA

13.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	l	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	VIL	—		2.0	—	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I _{OH} = -4 mA	3.0	2.48	—	
			I _{OH} = -8 mA	4.5	3.80	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	—	±2.50	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I _{CC}	V_{IN} = V_{CC} or GND		5.5	_	40.0	μA

13.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condi	ition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	VIL	_		2.0	—	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -50 μA	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I _{OH} = -4 mA	3.0	2.40	—	
			I _{OH} = -8 mA	4.5	3.70	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			I _{OL} = 4 mA	3.0	—	0.55	
			I _{OL} = 8 mA	4.5	—	0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5		80.0	μA

13.4. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}C$, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (SCK, RCK)	$t_{w(L)}, t_{w(H)}$	_	$\textbf{3.3}\pm\textbf{0.3}$	5.0	ns
			5.0 ± 0.5	5.0	
Minimum pulse width (SCLR)	t _{w(L)}	—	$\textbf{3.3}\pm\textbf{0.3}$	5.0	
			5.0 ± 0.5	5.0	
Minimum setup time (SI-SCK)	ts	_	$\textbf{3.3}\pm\textbf{0.3}$	3.5	ns
			5.0 ± 0.5	3.0	
Minimum setup time (SCK - RCK)	ts	_	$\textbf{3.3}\pm\textbf{0.3}$	8.0	
			5.0 ± 0.5	5.0	
Minimum setup time (SCLR -RCK)	ts	_	$\textbf{3.3}\pm\textbf{0.3}$	8.0	
			5.0 ± 0.5	5.0	
Minimum hold time (SI-SCK)	t _h	_	$\textbf{3.3}\pm\textbf{0.3}$	1.5	ns
			5.0 ± 0.5	2.0	
Minimum hold time (SCK-RCK)	t _h	_	$\textbf{3.3}\pm\textbf{0.3}$	0	
			5.0 ± 0.5	0	
Minimum hold time (SCLR-RCK)	t _h	_	$\textbf{3.3}\pm\textbf{0.3}$	0	
			5.0 ± 0.5	0	
Minimum removal time (SCLR)	t _{rem}	_	3.3 ± 0.3	3.0	ns
			5.0 ± 0.5	2.5	

13.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85°C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (SCK, RCK)	$t_{w(L)}, t_{w(H)}$	—	$\textbf{3.3}\pm\textbf{0.3}$	5.0	ns
			5.0 ± 0.5	5.0	
Minimum pulse width (SCLR)	t _{w(L)}	—	$\textbf{3.3}\pm\textbf{0.3}$	5.0	
			5.0 ± 0.5	5.0	
Minimum setup time (SI-SCK)	ts	—	$\textbf{3.3}\pm\textbf{0.3}$	3.5	ns
			5.0 ± 0.5	3.0	
Minimum setup time (SCK - RCK)	ts	_	3.3 ± 0.3	8.5	
			5.0 ± 0.5	5.0	
Minimum setup time (SCLR -RCK)	ts	—	3.3 ± 0.3	9.0	
			5.0 ± 0.5	5.0	
Minimum hold time (SI-SCK)	t _h	—	3.3 ± 0.3	1.5	ns
			5.0 ± 0.5	2.0	
Minimum hold time (SCK-RCK)	t _h	_	3.3 ± 0.3	0	
			5.0 ± 0.5	0	
Minimum hold time (SCLR-RCK)	t _h	_	3.3 ± 0.3	0	
			5.0 ± 0.5	0	
Minimum removal time (SCLR)	t _{rem}	_	3.3 ± 0.3	3.0	ns
			5.0 ± 0.5	2.5	

13.6. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (SCK, RCK)	t _{w(L)} ,t _{w(H)}	—	3.3 ± 0.3	5.0	ns
			5.0 ± 0.5	5.0	
Minimum pulse width (SCLR)	t _{w(L)}	_	3.3 ± 0.3	5.0	
			5.0 ± 0.5	5.0	
Minimum setup time (SI-SCK)	ts	_	3.3 ± 0.3	4.5	ns
			5.0 ± 0.5	3.5	
Minimum setup time (SCK - RCK)	ts	—	3.3 ± 0.3	9.0	
			5.0 ± 0.5	5.0	
Minimum setup time (SCLR -RCK)	ts	—	3.3 ± 0.3	10.0	
			5.0 ± 0.5	5.5	
Minimum hold time (SI-SCK)	t _h	—	3.3 ± 0.3	1.5	ns
			5.0 ± 0.5	2.0	
Minimum hold time (SCK-RCK)	t _h	—	3.3 ± 0.3	0	
			5.0 ± 0.5	0	
Minimum hold time (SCLR -RCK)	t _h	_	3.3 ± 0.3	0	
			5.0 ± 0.5	0	
Minimum removal time (SCLR)	t _{rem}	_	3.3 ± 0.3	4.0	ns
			5.0 ± 0.5	3.0	

13.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	$\textbf{3.3}\pm\textbf{0.3}$	15	—	8.8	13.0	ns
(SCK-QH')					50	_	11.3	16.5	
				5.0 ± 0.5	15	_	6.2	8.2	
					50	—	7.7	10.2	
Propagation delay time	t _{PHL}		—	$\textbf{3.3}\pm\textbf{0.3}$	15	_	8.4	12.8	ns
(SCLR -QH')					50	_	10.9	16.3	
				5.0 ± 0.5	15	_	5.9	8.0	
					50	_	7.4	10.0	
Propagation delay time	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	7.7	11.9	ns
(RCK-Q _n)					50	_	10.2	15.4	
				5.0 ± 0.5	15	_	5.4	7.4	
					50	_	6.9	9.4	
3-state output enable time	t _{PZL} ,t _{PZH}		R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	15	_	7.5	11.5	ns
					50	_	9.0	15.0	
				5.0 ± 0.5	15	_	4.8	8.6	
					50	_	8.3	10.6	
3-state output disable time	t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	3.3 ± 0.3	50	_	12.1	15.7	ns
				5.0 ± 0.5	50	_	7.6	10.3	
Maximum clock frequency	f _{MAX}		_	3.3 ± 0.3	15	80	150	_	MHz
					50	55	130	_	
				5.0 ± 0.5	15	135	185	_	
					50	95	155	_	
Input capacitance	C _{IN}			•		_	4	10	рF
Output capacitance	C _{OUT}		_			_	6	_	
Power dissipation capacitance	C _{PD}	(Note 1)	_			_	87	_	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

13.8. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	15.0	ns
(SCK-QH')				50	1.0	18.5	
			5.0 ± 0.5	15	1.0	9.4	1
				50	1.0	11.4]
Propagation delay time	t _{PHL}	-	3.3 ± 0.3	15	1.0	13.7	ns
(SCLR -QH')				50	1.0	17.2	1
			5.0 ± 0.5	15	1.0	9.1]
				50	1.0	11.1	
Propagation delay time	t _{PLH} ,t _{PHL}	_	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	13.5	ns
(RCK-Q _n)				50	1.0	17.0	
			5.0 ± 0.5	15	1.0	8.5	
				50	1.0	10.5]
3-state output enable time	t _{PZL} ,t _{PZH}	R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	13.5	ns
				50	1.0	17.0	
			5.0 ± 0.5	15	1.0	10.0]
				50	1.0	12.0]
3-state output disable time	t _{PLZ} ,t _{PHZ}	R _L = 1 kΩ	3.3 ± 0.3	50	1.0	16.2	ns
			5.0 ± 0.5	50	1.0	11.0]
Maximum clock frequency	f _{MAX}	_	$\textbf{3.3}\pm\textbf{0.3}$	15	70	—	MHz
				50	50		
			5.0 ± 0.5	15	115	_]
				50	85	_]
Input capacitance	C _{IN}	_			_	10	pF

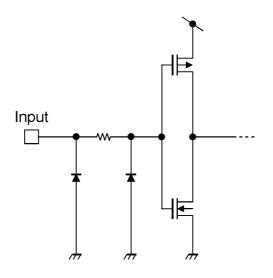
13.9. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	17.5	ns
(SCK-QH')				50	1.0	21.0	
			5.0 ± 0.5	15	1.0	11.0	1
				50	1.0	13.0]
Propagation delay time	t _{PHL}	_	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	17.0	ns
(SCLR -QH')				50	1.0	20.5	
			5.0 ± 0.5	15	1.0	10.5	1
				50	1.0	12.5	ns ns ns ns
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	16.0	ns
RCK-Q _n)				50	1.0	19.5	1
			5.0 ± 0.5	15	1.0	10.0	
				50	1.0	12.0	
3-state output enable time	t _{PZL} ,t _{PZH}	R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	15.5	ns
				50	1.0	19.0	1
			5.0 ± 0.5	15	1.0	11.5	1
				50	1.0	13.5	1
3-state output disable time	t _{PLZ} ,t _{PHZ}	R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	20.0	ns
			5.0 ± 0.5	50	1.0	13.0	1
Maximum clock frequency	f _{MAX}	_	$\textbf{3.3}\pm\textbf{0.3}$	15	60	_	MHz
				50	40	_	-
			5.0 ± 0.5	15	105	_	
				50	75	_	1
Input capacitance	C _{IN}	_			_	10	pF

13.10. Noise Characteristics (Unless otherwise specified, $T_a = 25^{\circ}C$, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	

14. Input Equivalent Circuit

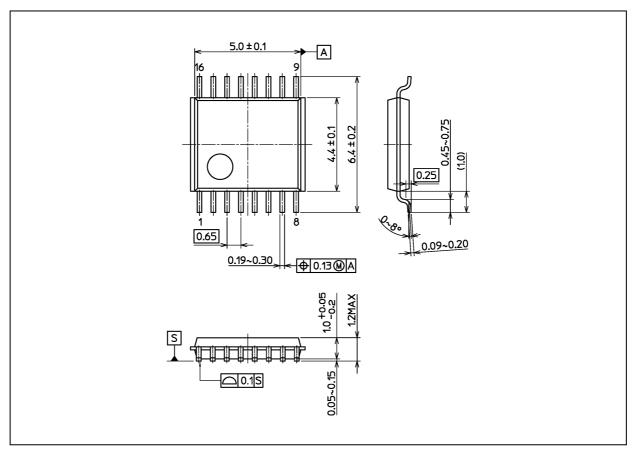




74VHC595FT

Package Dimensions

Unit: mm



Weight: 0.055 g (typ.)

	Package Name(s)
Nickname: TSSOP16B	

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ООО "ЛайфЭлектроникс"

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 3010181090000000703 БИК 044030703

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С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

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- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
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- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
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